



A Review of Biasing Conditions for Standard Junction Diode and its Characteristics

¹Atul Kumar Gupta , ²K. K. Tiwari

Department of Physics, Allahabad Degree College
University of Allahabad, India , email : atulkumar_physics@rediffmail.com

Abstract : A *PN Junction Diode* is one of the simplest semiconductor devices around, and which has the characteristic of passing current in only one direction only. However, unlike a resistor, a diode does not behave linearly with respect to the applied voltage as the diode has an exponential current-voltage (I-V) relationship and therefore we can not described its operation by simply using an equation such as Ohm's law.

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If a suitable positive voltage (forward bias) is applied between the two ends of the PN junction, it can supply free electrons and holes with the extra energy they require to cross the junction as the width of the depletion layer around the PN junction is decreased.

By applying a negative voltage (reverse bias) results in the free charges being pulled away from the junction resulting in the depletion layer width being increased. This has the effect of increasing or decreasing the effective resistance of the junction itself allowing or blocking current flow through the diode.

Then the depletion layer widens with an increase in the application of a reverse voltage and narrows with an increase in the application of a forward voltage. This is due to the differences in the electrical properties on the two sides of the PN junction resulting in physical changes taking place.

Key Words : *PN Junction Diode* , Zero Bias , Reverse Bias , Forward Bias